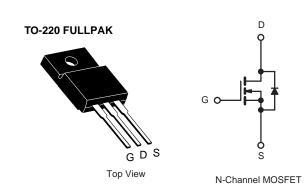


N-Channel 650 V (D-S) Super Junction Power MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	R _{DS(on)} (mΩ)(Max.)	I _D (A)	Q _g (Typ.)			
650	190 at V _{GS} = 10 V	20	44 nC			





FEATURES

- DT-SJ Power MOSFET
- 100 % Rg and UIS tested
- Low R_{DS(ON)}×FOM
- · Extremely low switching loss
- Excellent stability and uniformity

APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage(Typ.)	V _{DS}	650	V		
Gate-Source Voltage	V _{GS}	± 30	V		
Continuous Drain Current (T _{.1} = 150 °C) ^a	T _C = 25 °C	I _D	20		
Continuous Drain Current (1) = 130 C)	T _C = 100 °C	'D	13	A	
Pulsed Drain Current ^b		I _{DM}	60		
Single Avalanche Energy ^e		E _{AS}	390	mJ	
Maximum Power Dissipation ^c	T _C = 25 °C	$ P_{D}$	27	W	
Maximum Fower Dissipation	T _C = 100 °C	r D	10.8		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +150	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER	SYMBOL	LIMIT	UNIT		
Junction-to-Ambient (PCB Mount) ^d	R _{thJA}	50.6	°C/W		
Junction-to-Case (Drain)	R _{thJC}	4.6	C/VV		

Notes

- a. Calculated continuous current based on maximum allowablejunction temperature.
- b. Repetitive rating; pulse width limited by max. junction temperature.
- c. Pd is based on max. junction temperature, using junction-case thermal resistance.
- d. The value of R_{0JA} is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper,in a still air environment with Ta=25 °C.
- e. V_{DD} =150 V, V_{GS} =10 V, L=10.8 mH, starting T_j =25 °C.



PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	650	-	-	V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2.6	-	4	V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 30 \text{ V}$	-	-	± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 650 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	10	μΑ
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, I_D = 10 \text{ A}$	-	140	190	
Drain Gourge on Grate Resistance	US(on)	V _{GS} = 10 V, I _D = 10 A,T _j =150 °C	-	390	-	mΩ
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 4 A	-	9	-	S
Dynamic ^b						
Input Capacitance	C _{iss}		-	1670	-	
Output Capacitance	C _{oss}	$V_{GS} = 0 \text{ V}, V_{DS} = 100 \text{ V}, f = 100 \text{ KHz}$	-	83	-	pF
Reverse Transfer Capacitance	C _{rss}		-	0.8	-	
Total Gate Charge ^c	Qg		-	4	-	
Gate-Source Charge ^c	Q_{gs}	$V_{DS} = 520 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 10 \text{ A}$	-	9	-	nC
Gate-Drain Charge ^c	Q _{gd}		-	18	-	
Gate Resistance	R_g	f = 1 MHz	-	20	-	Ω
Turn-On Delay Time ^c	t _{d(on)}		-	50	-	
Rise Time ^c	t _r	$V_{DD} = 520 \text{ V}, I_D = 20 \text{ A},$	-	61	-	
Turn-Off Delay Time ^c	t _{d(off)}	$V_{GEN}=10~V,~R_{g}=25\Omega$	-	195	-	ns
Fall Time ^c	t _f		-	55	-	
Drain-Source Body Diode Ratings ar	nd Characteris	stics ^b (T _C = 25 °C)				
Continuous Source Current	I _S	T _C = 25 °C	-	-	20	А
Pulsed Current (t = 100 μs)	I _{SM}		-	-	60	Α
Forward Voltage ^a	V_{SD}	$I_S = 8 \text{ A}, V_{GS} = 0 \text{ V}$	-	-	1.2	V
Reverse Recovery Time	t _{rr}		-	350	-	ns
Reverse Recovery Charge	Q _{rr}	$I_S = 20 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$	-	6.2	-	μC
Peak reverse recovery current	I _{rrm}		-	-36	-	Α

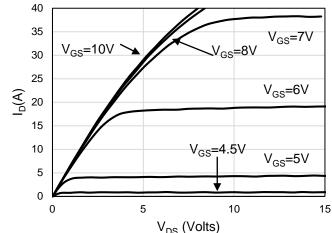
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

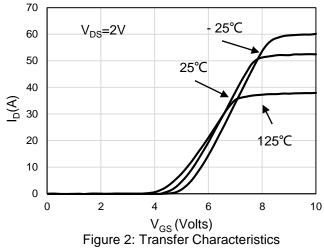
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



 V_{DS} (Volts) Figure 1: On-Region Characteristics



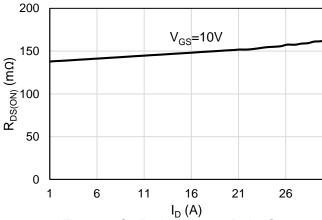


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

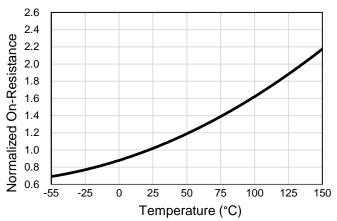
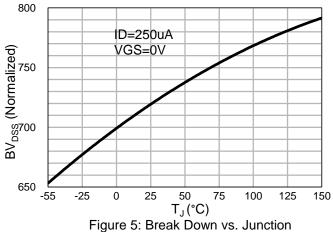
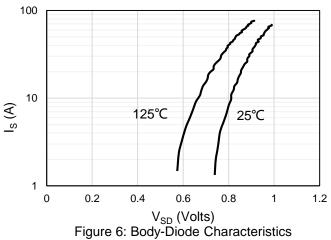


Figure 4: On-Resistance vs. Junction Temperature

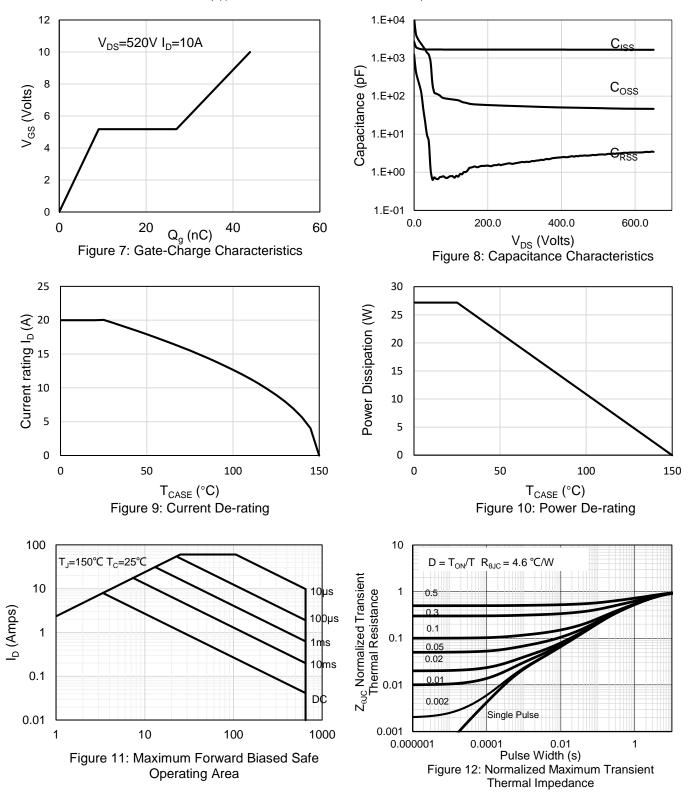


Temparature



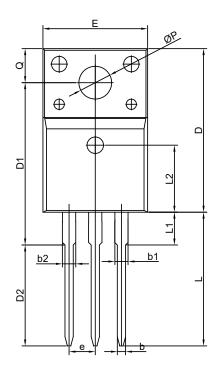


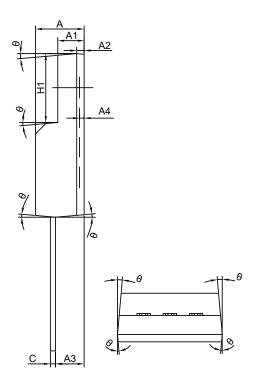
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

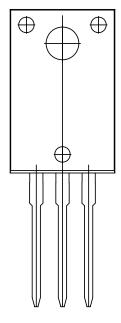




TO-220F-3L PACKAGE OUTLINE







COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
Α	4.30	4.72	5.10
A1	2.25	2.56	2.90
A2	0.72 REF		
A3	2.28 2.78 3.50		
A4	C).45 MA)	<
b	0.65	-	0.95
b1	1.00	-	1.55
b2	-	-	1.55
С	0.40	0.50	0.65
D	15.47	15.87	16.37
D1	15.35	15.75	16.25
Е	9.76	10.16	10.76
е	2.54 BSC		
H1	6.28	6.68	7.08
L	12.48	12.98	13.50
L1	2.90	-	3.80
L2	2.54 BSC		
ØP	2.98	3.18	3.50
Q	3.00	-	3.60
θ	3°	5°	7°





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